TOSHIBA Field Effect Transistor Silicon N Channel MOS Type ( $\pi$ -MOSIV)

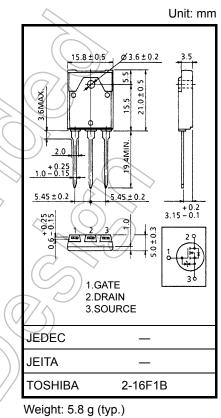
# 2SK3453

#### Switching Regulator Applications

- Low drain-source ON-resistance: R<sub>DS (ON)</sub> = 0.72 Ω (typ.)
- High forward transfer admittance: |Y<sub>fs</sub>| = 7.0 S (typ.)
- Low leakage current:  $I_{DSS}$  = 100  $\mu$ A (max) (V<sub>DS</sub> = 700 V)
- Enhancement model:  $V_{th}$  = 2.0 to 4.0 V ( $V_{DS}$  = 10 V,  $I_D$  = 1 mA)

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit		
Drain-source voltage		V <sub>DSS</sub>	700	$(N \land$	$\geq$	
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		V <sub>DGR</sub>	700	V		
Gate-source voltage			V <sub>GSS</sub>	±30	Vy I	
Drain current	DC	(Note 1)	۱ <sub>D</sub>	10		
	Pulse	(Note 1)	I <sub>DP</sub>	30	× A	
Drain power dissipation (Tc = $25^{\circ}$ C)			PD	80	W	(
Single pulse avalanche energy (Note 2)			EAS	420	mJ	//
Avalanche current		I <sub>AR</sub> 10		A		
Repetitive avalanche energy (Note 3)			E <sub>AR</sub> 8		mJ	$\geq$
Channel temperature			Tch	150	°C	
Storage temperature range			T <sub>stg</sub>	-55 to 150	)°C	



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th</sub> (ch-c)	1.56	°C/W
Thermal resistance, channel to ambient	Rth (ch-a)	41.6	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:  $V_{DD} = 90 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}$  (initial), L = 7.5 mH, R<sub>G</sub> = 25  $\Omega$ , I<sub>AR</sub> = 10 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

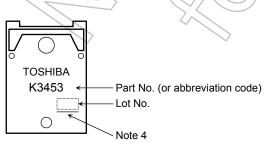
**Electrical Characteristics (Ta = 25°C)** 

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I <sub>GSS</sub>	$V_{GS}=\pm 25~V,~V_{DS}=0~V$	_		±10	μA
Gate-source brea	akdown voltage	V (BR) GSS	$I_G=\pm 10~\mu A,~V_{DS}=0~V$	±30		_	V
Drain cut-OFF cu	rrent	IDSS	$V_{DS} = 700 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	X		100	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	700	-		V
Gate threshold vo	oltage	V <sub>th</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.0	)}(	4.0	V
Drain-source ON resistance		R <sub>DS (ON)</sub>	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 5 \text{ A}$	K	0.72	1.0	Ω
Forward transfer admittance		Y <sub>fs</sub>	$V_{DS} = 10 V, I_D = 5 A$	4.0	7.0		S
Input capacitance		C <sub>iss</sub>			1700		
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 25 V$ , $V_{GS} = 0 V$ , f = 1 MHz	<u> </u>	40		pF
Output capacitance		C <sub>oss</sub>			200		
Switching time	Rise time	tr		_ (	40		
	Turn-ON time	t <sub>on</sub>	$0 V \longrightarrow R_L = 40 \Omega$	C X	72	) _	20
	Fall time	tf	Duty $\leq$ 1%, t <sub>W</sub> = 10 µs	$\overline{\mathcal{A}}$	42		ns
	Turn-OFF time	t <sub>off</sub>		) _	145		
Total gate charge (gate-source plus gate-drain)		Qg			53		
Gate-source charge		Qgs	V <sub>DD</sub> ≈ 400 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 10 A	_	25	_	nC
Gate-drain ("miller") charge		Q <sub>gd</sub>			28		

## Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>		_	_	10	А
Pulse drain reverse current (Note 1)	IDRP		_	_	30	А
Forward voltage (diode)	V <sub>DSF</sub>	I <sub>DR</sub> = 10 A, V <sub>GS</sub> = 0 V	_	_	-1.9	V
Reverse recovery time	∕ <sup>t</sup> rr	I <sub>DR</sub> = 10 A, V <sub>GS</sub> = 0 V,	_	1400	_	ns
Reverse recovery charge	Qrr	dI <sub>DR</sub> /dt = 100 A/μs	_	17.5	_	μC

#### Marking

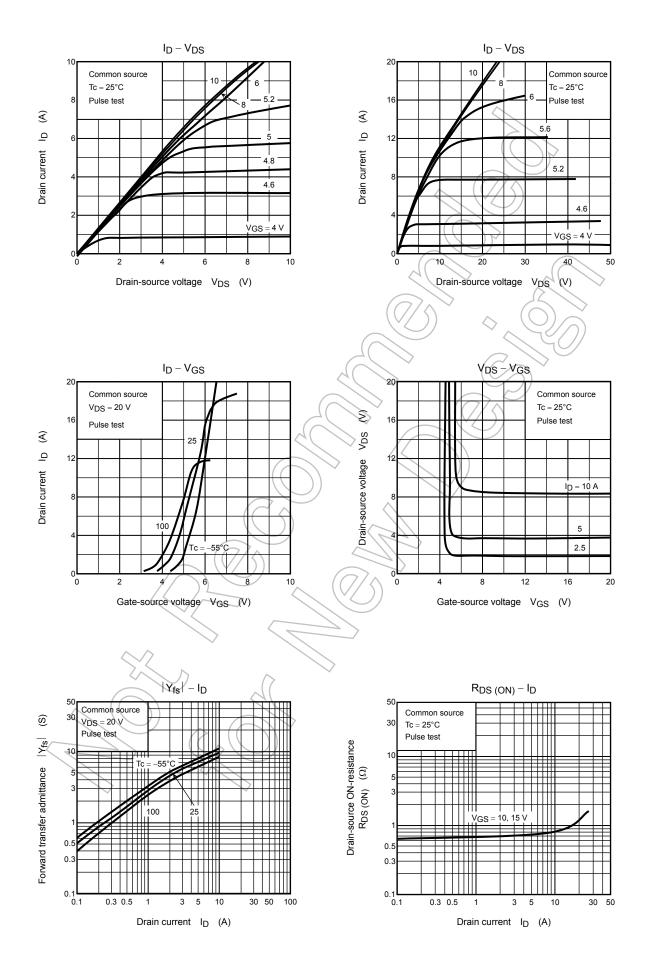


Note 4: A line under a Lot No. identifies the indication of product Labels.

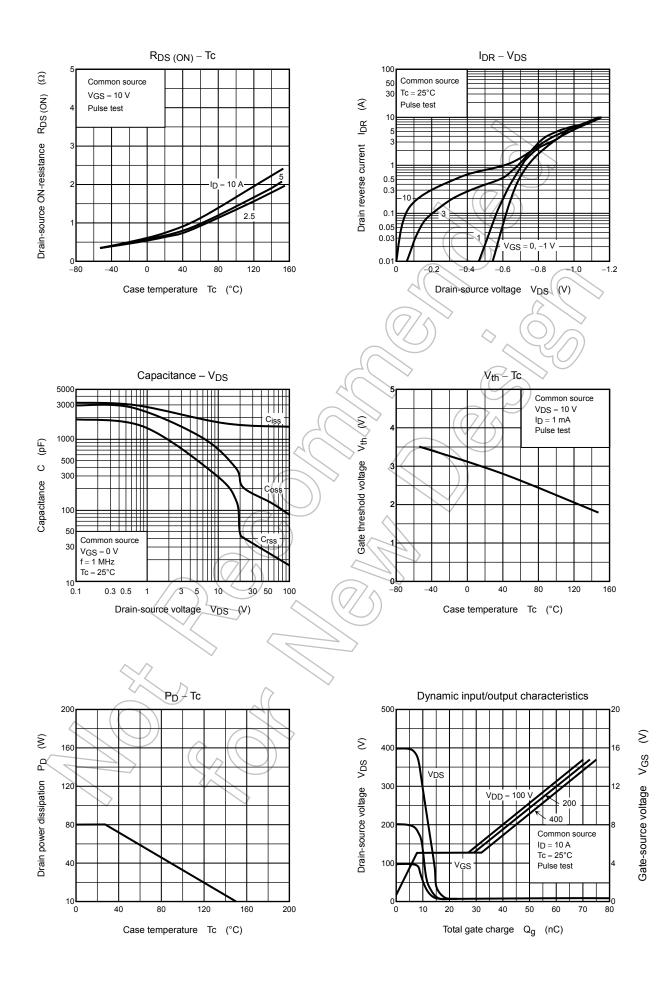
Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

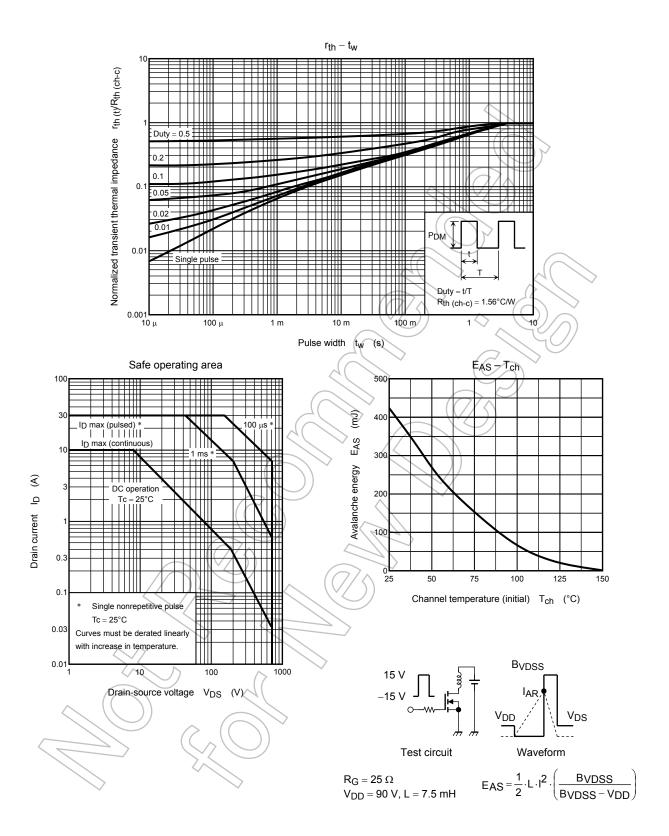
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